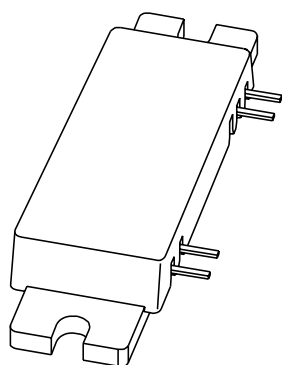


DATA SHEET



BGY1916 UHF amplifier module

Product specification
Supersedes data of 1998 Apr 09

1998 May 27

UHF amplifier module

BGY1916

FEATURES

- 26 V nominal supply voltage
- 16 W output power into a load of 50 Ω with an RF drive power of ≤63 mW.

APPLICATIONS

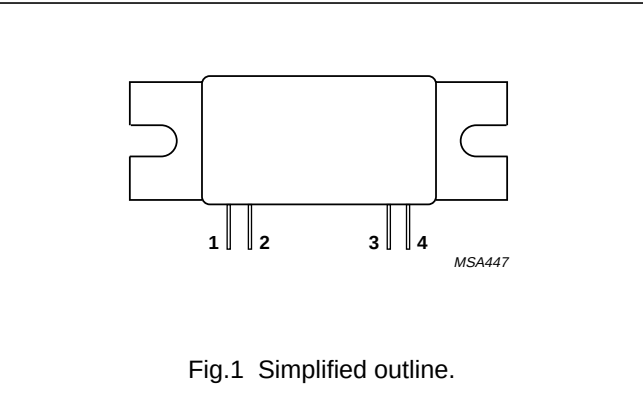
- Base station transmitting equipment operating in the 1930 to 1990 MHz frequency band.

DESCRIPTION

The BGY1916 is a three-stage UHF amplifier module in a SOT365A package with a plastic cap. It consists of three NPN silicon planar transistor dies mounted together with matching and bias circuit components on a metallized ceramic AlN substrate.

PINNING - SOT365A

PIN	DESCRIPTION
1	RF input
2	V _{S1}
3	V _{S2}
4	RF output
Flange	ground



QUICK REFERENCE DATA

RF performance at T_{mb} = 25 °C.

MODE OF OPERATION	f (MHz)	V _{S1} (V)	V _{S2} (V)	P _L (W)	G _p (dB)	η (%)	Z _S ; Z _L (Ω)
CW	1930 to 1990	5	26	≥16	≥24	≥30	50

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{S1}	DC supply voltage		4.5	5.5	V
V _{S2}	DC supply voltage		–	28	V
P _D	input drive power		–	120	mW
P _L	load power	T _{mb} = 25 °C	–	20	W
T _{stg}	storage temperature		–30	+100	°C
T _{mb}	operating mounting base temperature		–10	+90	°C

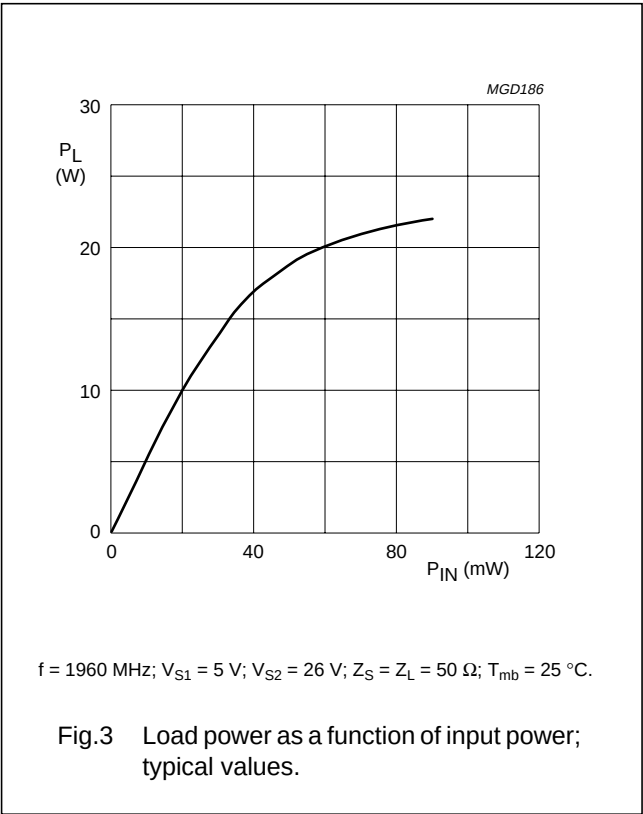
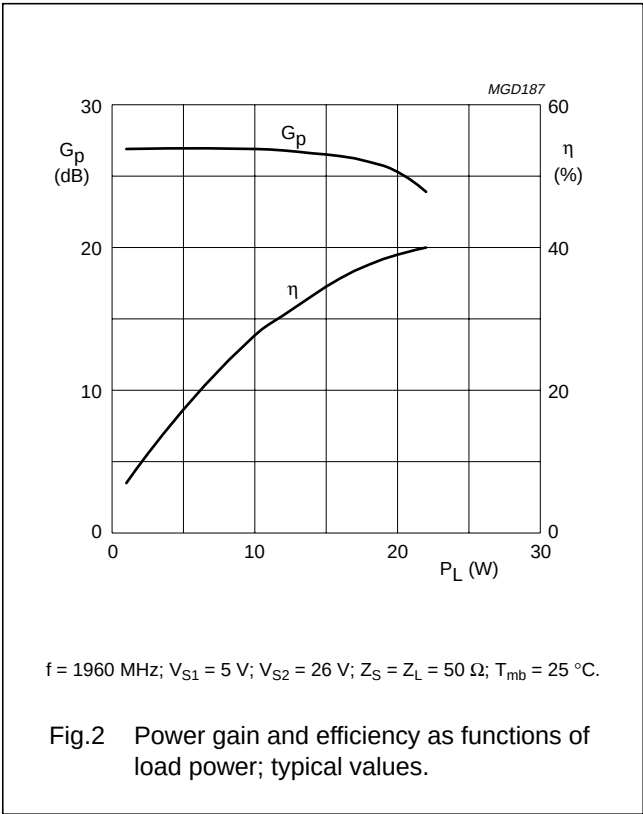
UHF amplifier module

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CHARACTERISTICS

$T_{mb} = 25\text{ }^{\circ}\text{C}$; $V_{S1} = 5\text{ V}$; $V_{S2} = 26\text{ V}$; $P_L = 16\text{ W}$; $Z_S = Z_L = 50\text{ }\Omega$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency		1930	–	1990	MHz
I _{S1}	supply current		–	80	–	mA
I _{S2}	supply current	$P_D < -60\text{ dBm}$	–	430	–	mA
P _L	load power	$P_D < 63\text{ mW}$	16	–	–	W
G _p	power gain		24	–	28	dB
η	efficiency		30	–	–	%
H ₂	second harmonic		–	–	–35	dBc
H ₃	third harmonic		–	–	–45	dBc
VSWR _{in}	input VSWR		–	–	1.6 : 1	
	stability	VSWR ≤ 2 : 1 through all phases; P _L ≤ 16 W; V _{S2} = 25 to 27 V	–	–	–60	dBc
	reverse intermodulation	P _{carrier} = 16 W; P _{reverse} = –40 dBc; f _i = f _c ±200 kHz	–	–	–53	dBc
B	AM bandwidth	corner frequency = 3 dB; P _{carrier} = 16 W; modulation = 20%	2	–	–	MHz
	ruggedness	VSWR ≤ 5 : 1 through all phases	no degradation			



UHF amplifier module

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APPLICATION INFORMATION

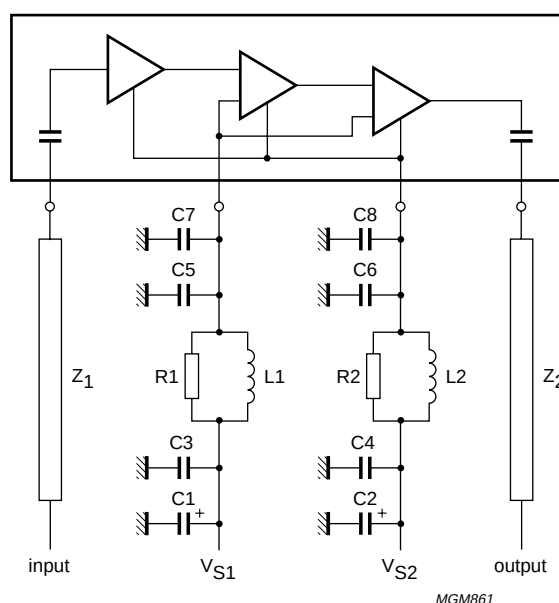


Fig.4 Test circuit.

List of components (see Figs 4 and 5)

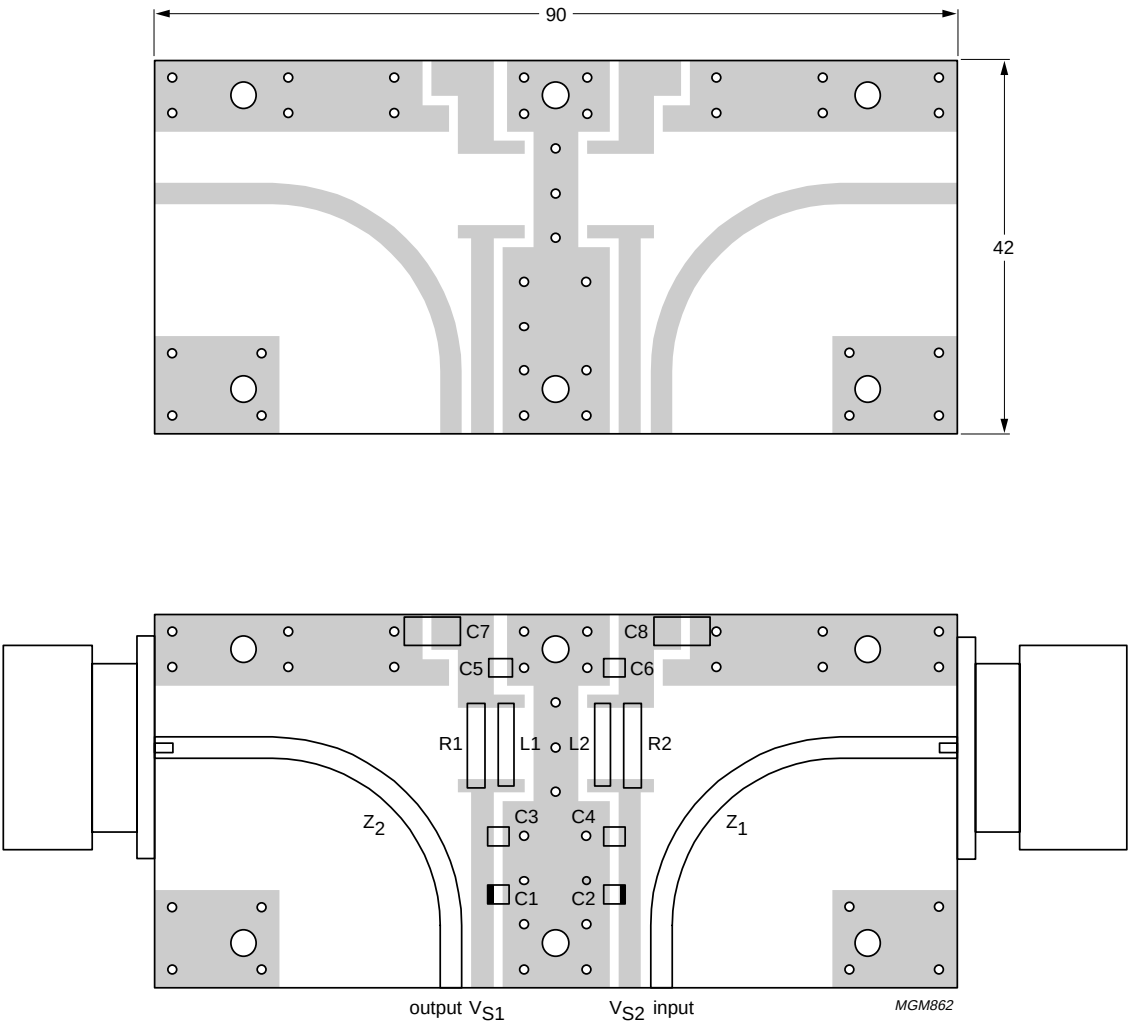
COMPONENT	DESCRIPTION	VALUE	CATALOGUE NO.
C1, C2	electrolytic capacitor	10 μ F; 35 V	
C3, C4	multilayer ceramic chip capacitor	10 nF; 50 V	
C5, C6	multilayer ceramic chip capacitor	100 pF; 50 V	
C7, C8	multilayer ceramic chip capacitor	10 pF; 50 V	
L1, L2	Grade 4S2 Ferroxcube bead		4330 030 36300
R1, R2	metal film resistor	10 Ω ; 0.4 W	2322 195 13109
Z ₁ , Z ₂	stripline: note 1	50 Ω	

Note

1. The striplines are on a double copper-clad printed-circuit board with epoxy dielectric ($\epsilon_r = 4.5$); thickness = 1 mm.

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Dimensions in mm.

Fig.5 Printed-circuit board component layout.

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MOUNTING RECOMMENDATIONS

To ensure a good thermal contact and to prevent mechanical stress when bolted down, the flatness of the mounting base is designed to be typically better than 0.1 mm. The mounting area of the heatsink should be flat and free from burrs and loose particles. The heatsink should be rigid and not prone to bowing under thermal cycling conditions. The thickness of a solid heatsink should be not less than 5 mm to ensure a rigid assembly.

A thin, even layer of thermal compound should be applied between the mounting base and the heatsink to achieve the best possible thermal contact resistance. Excessive use of thermal compound will result in an increase in thermal resistance and possible bowing of the mounting base; too little will also result in poor thermal conduction.

The module should be mounted to the heatsink using 3 mm bolts with flat washers. The bolts should first be tightened to “finger tight” and then further tightened in alternating steps to a maximum torque of 0.4 to 0.6 Nm.

Once the module is mounted on the heatsink, the leads can be soldered to the printed-circuit board. A soldering iron may be used up to a temperature of 250 °C for a maximum of 10 seconds at a distance of 2 mm from the plastic cap.

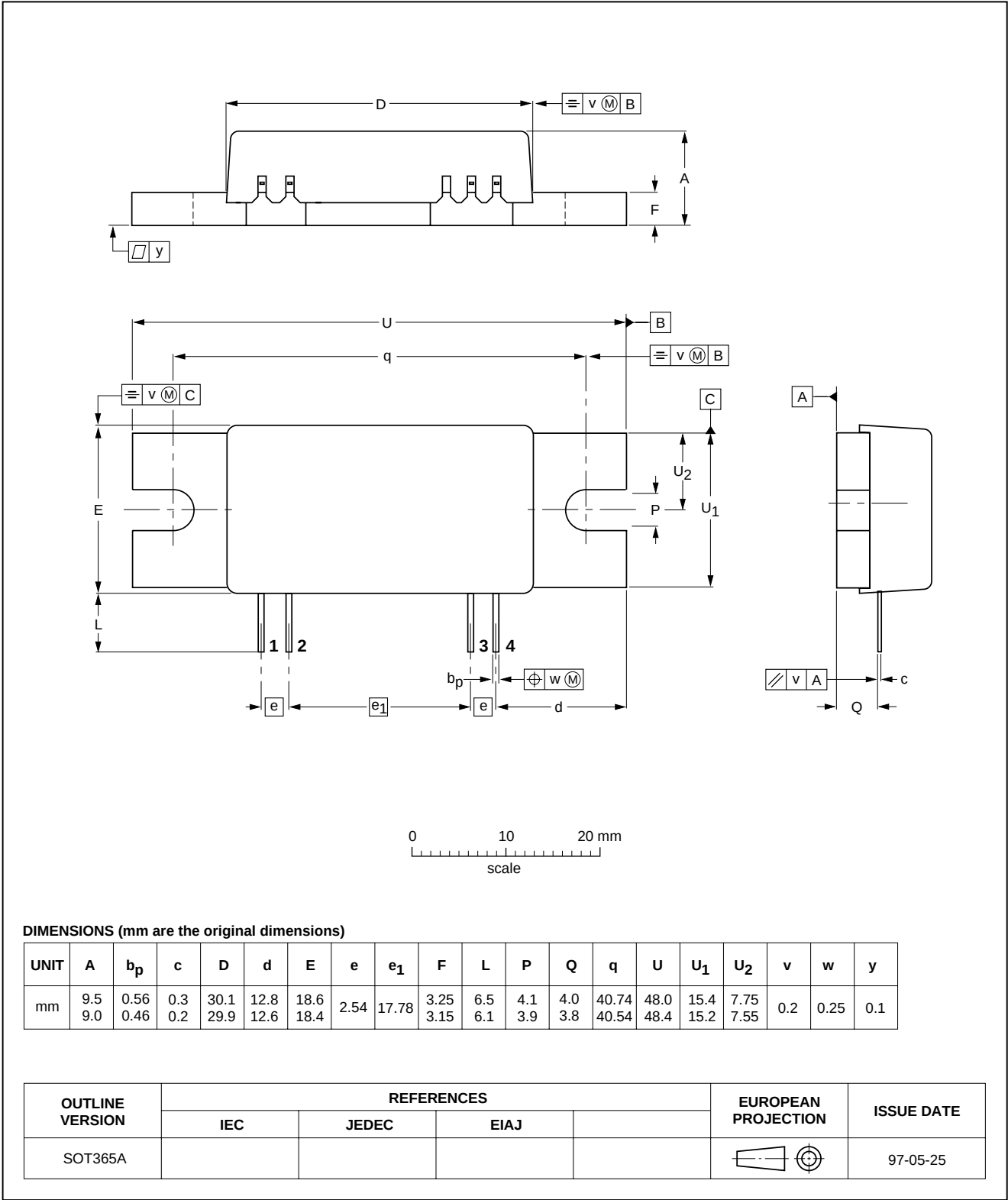
Precautions must be taken to protect the device from electrostatic damage (ESD).

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PACKAGE OUTLINE

Plastic rectangular single-ended flat package; flange mounted; 2 mounting holes; 4 in-line leads SOT365A



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DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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NOTES

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NOTES

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